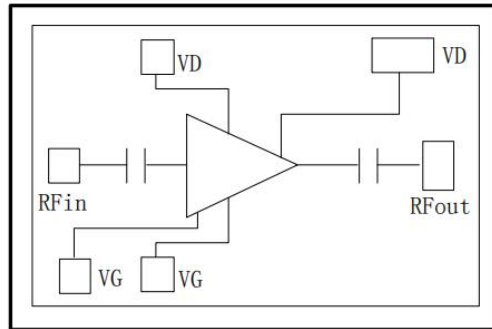


### Performance

- Frequency: 2.7~3.5GHz
- Typical Signal Gain: 31dB
- Typical Pout: 41.5dBm@28V
- Typical PAE: 50%
- Mode: CW
- Typical Operating Current: 1.2A
- Bias: 28V, -2.3~-1.9V (Typ.)
- Technology: 0.25um PHEMT
- Size: 3.3\*2.3mm\*0.08mm

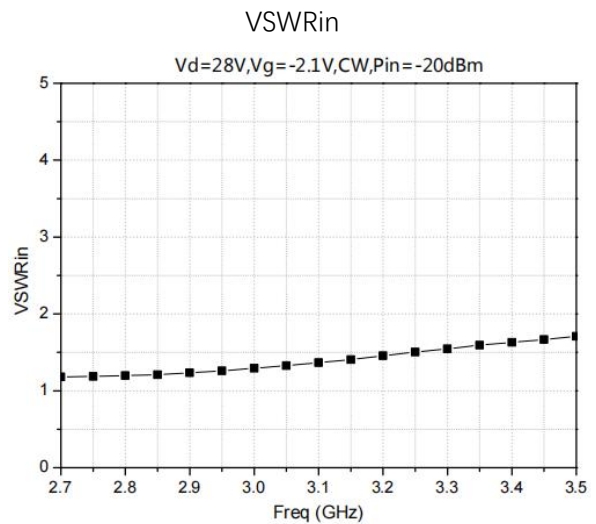
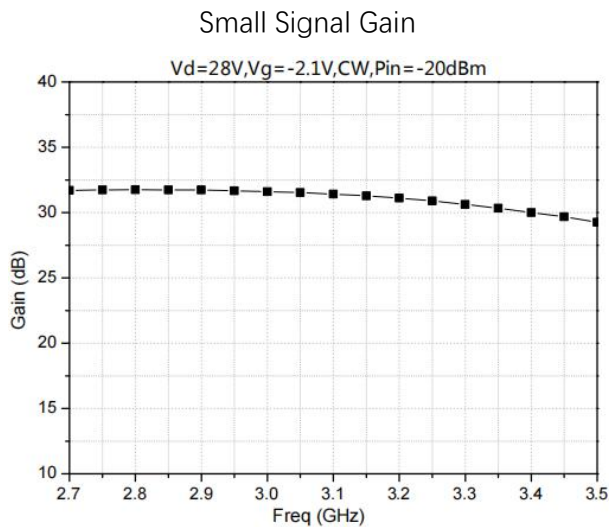
### Function Diagram

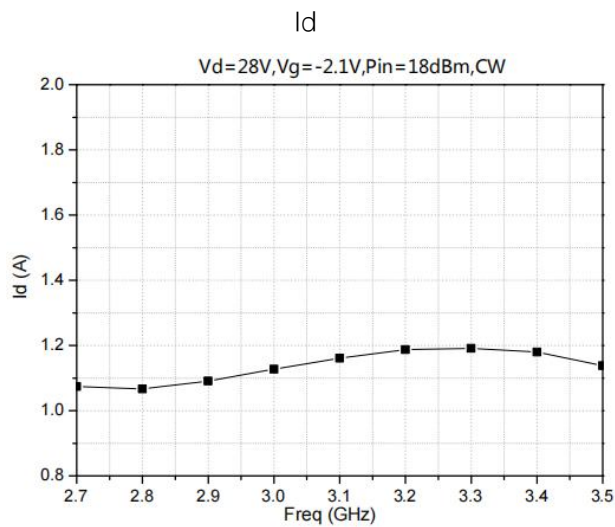
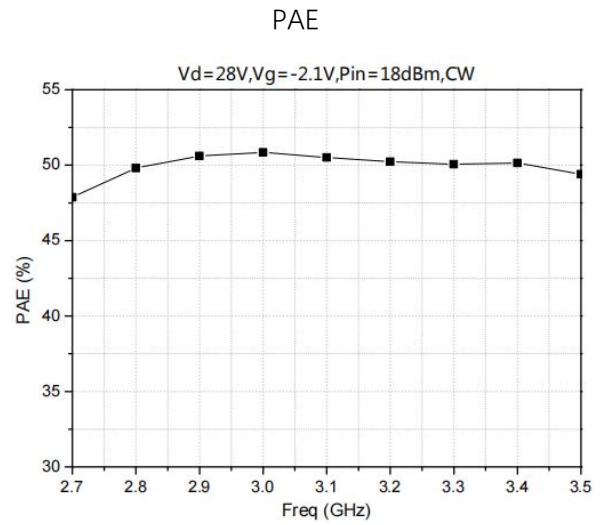
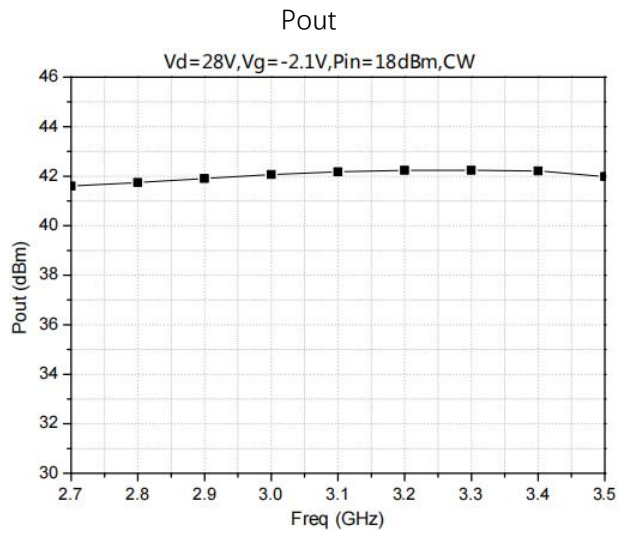


### Electrical Specifications (TA=25°C, Vd=28V, Vg=-2.1V, F: 2.7~3.5GHz, Pin=18dBm, CW)

Symbol	Parameter	Min	Typical	Max	Unit
G	Small Signal Gain	-	31	-	dB
Gp	Power Gain	23	23.5	-	dB
Pout	Saturated Power	41	41.5	-	dBm
PAE	Power Added Efficiency	47	50	52	%
Id	Dynamic current	-	1.2	-	A

### Test Curves

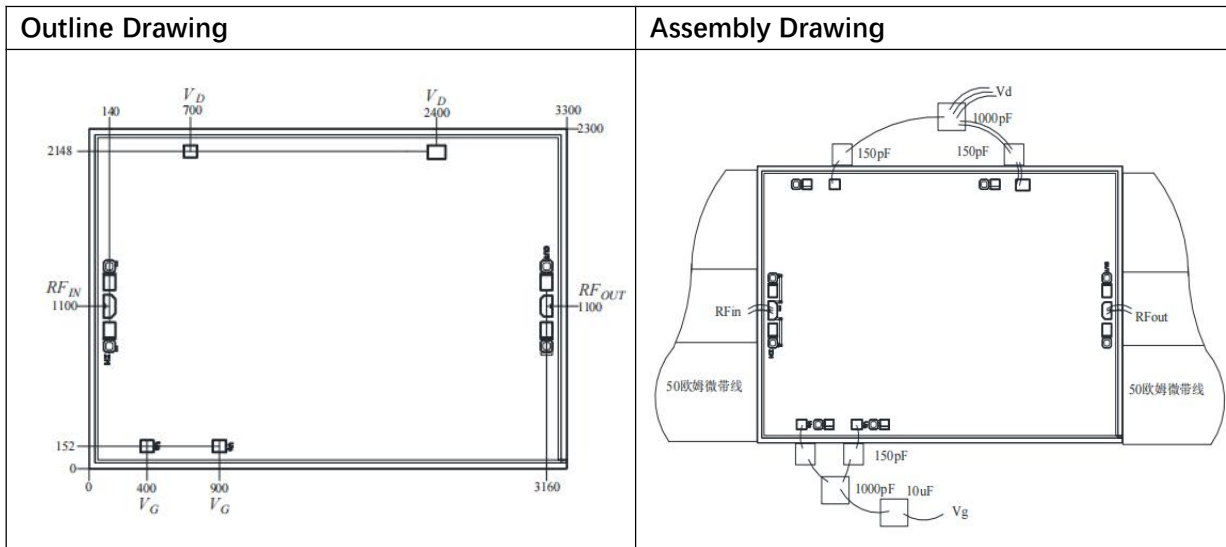




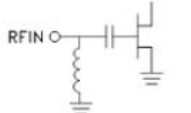

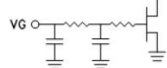

#### Absolute Max Ratings (TA=25°C)

Symbol	Parameter	Value	Remark
Vd	Drain Voltage	32V	
Vg	Grid Voltage	-10V	
Pd	DC Power	45W	
Pin	Input Power	26dBm	
Tch	Channel Temperature	225°C	
Tm	Mounting Temperature	310°C	30 s, N2 Protection
Tstg	Storage Temperature	-65~150°C	

Exceeding any one or combination of these limits may cause permanent damage.



### Pads Definition

Pad	Description	Equivalent Circuit
RFIn	RF Signal input, connect to 50ohm system, block capacitor is needed if there's external DC applied on this pad.	
RFout	RF Signal output, connect to 50ohm system, no need block capacitor.	
VG	Amp gate bias, external 150pF, 1000pF,10uF capacitor is needed	
VD	Amp drain bias, external 150pF, 1000pF capacitor is needed	
GND	Bottom must connect to RF and DC ground	